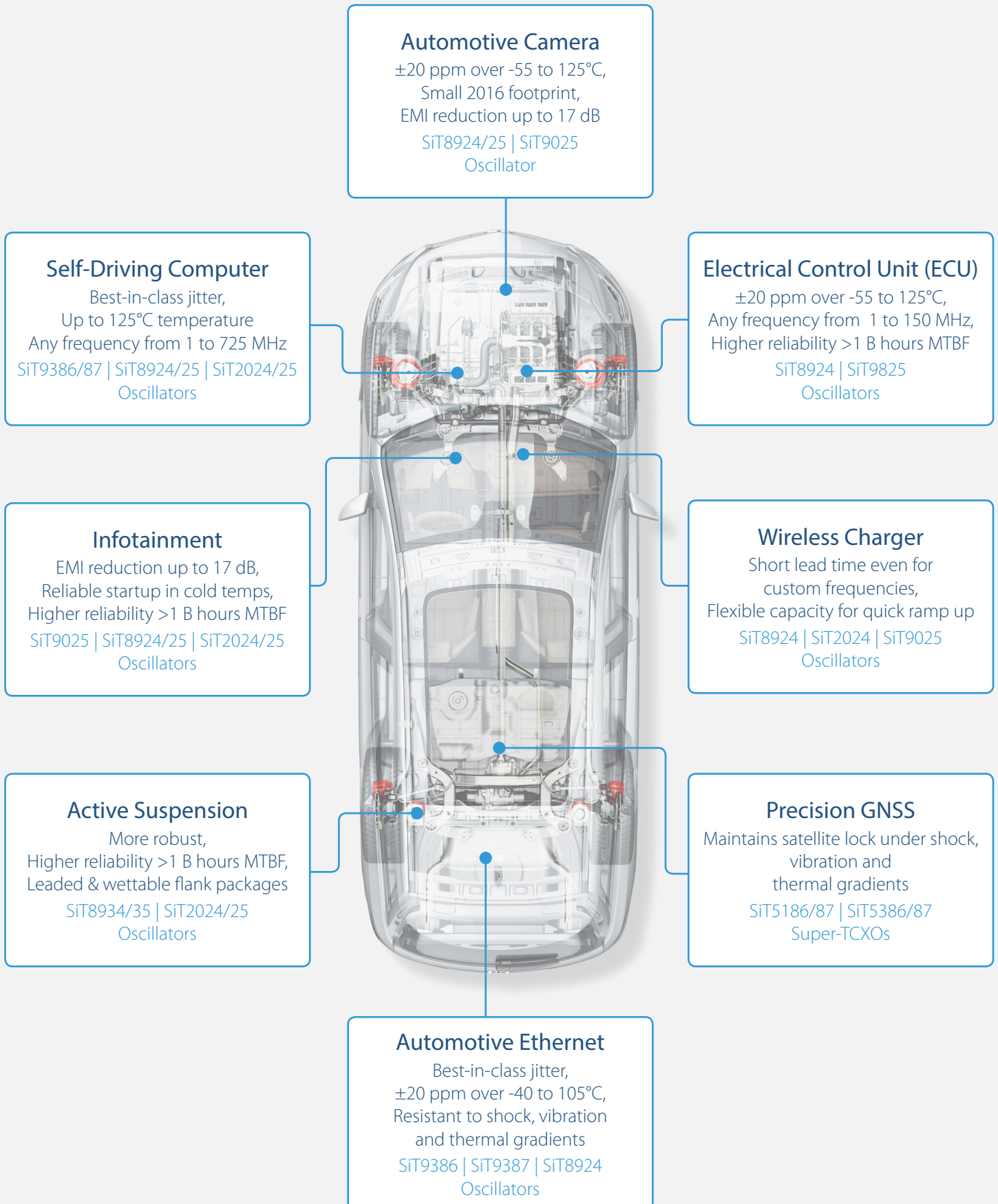




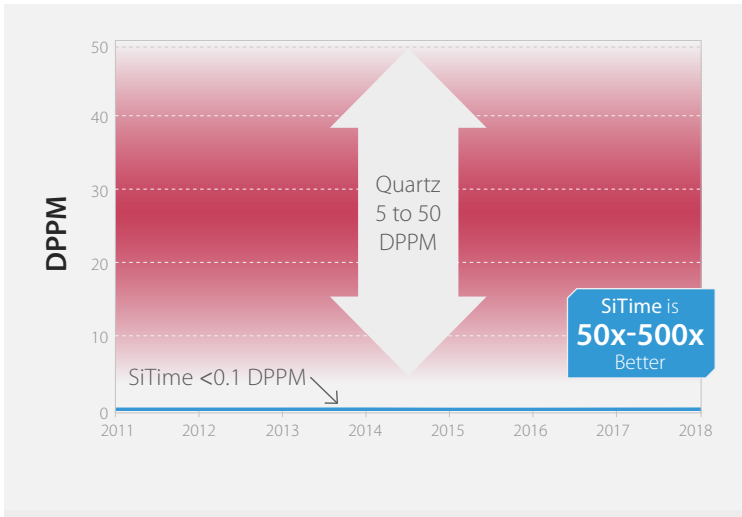
MEMS Timing Solutions for **Automotive**

- Best-in-class performance in harsh environments
- Higher quality and reliability, AEC-Q100 compliant
- Programmable, instant samples, short lead time

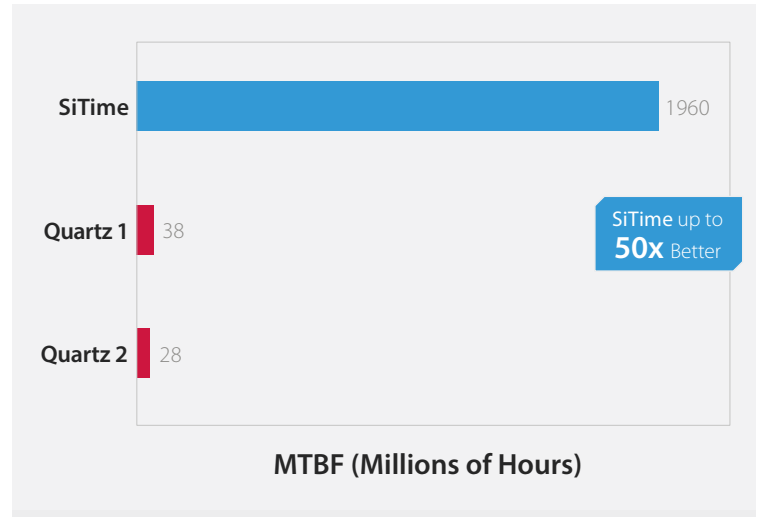
A small part from SiTime
runs a big part of
your world



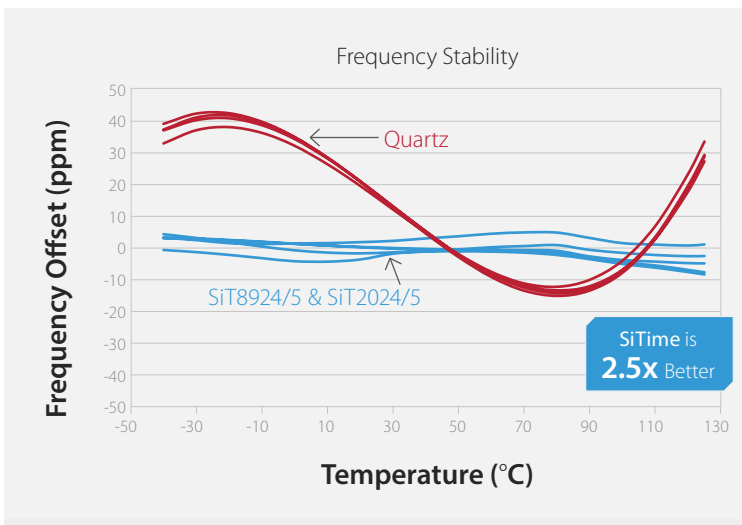
Higher Quality



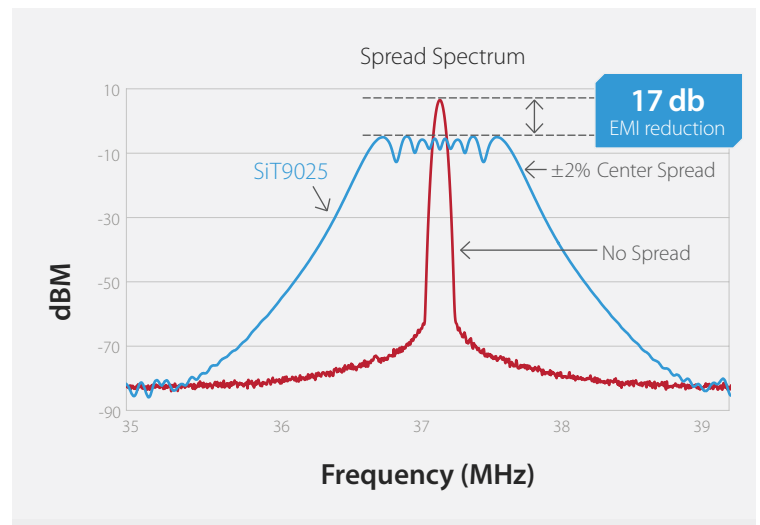
Higher Reliability



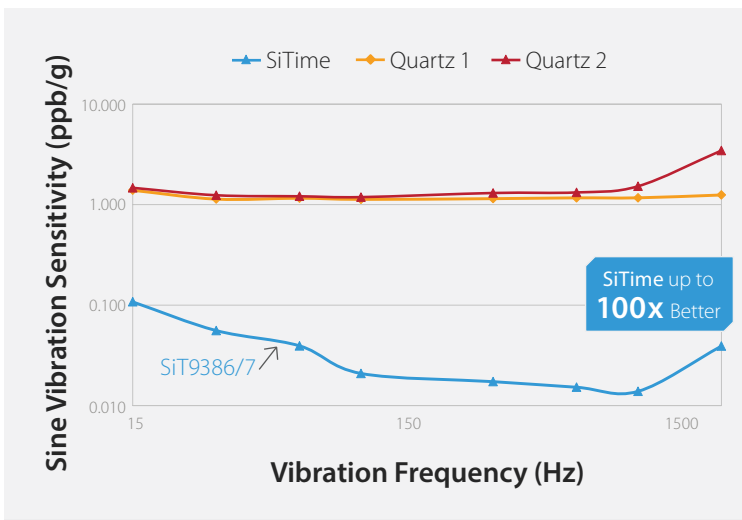
Tighter Stability



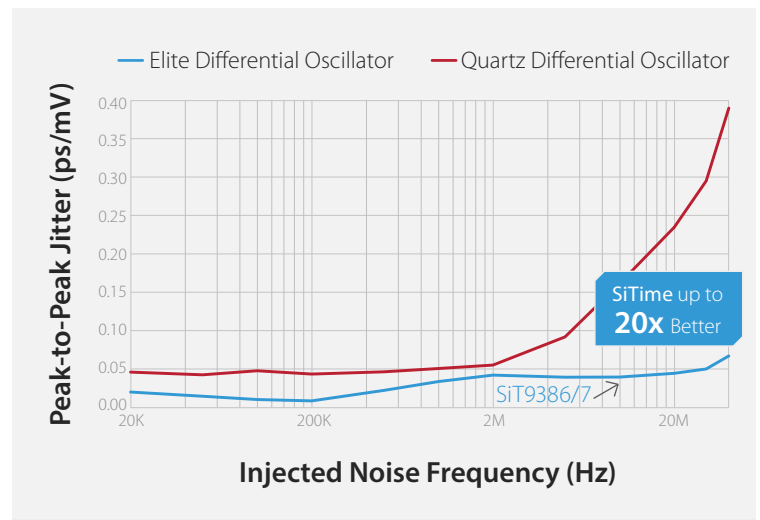
Better EMI Reduction



Immune to Vibration



Better Noise Rejection



SiTime Base Part No.	Output Frequency	Temperature Range (°C)	Frequency Stability (ppm)	Supply Voltage (V)	Packages (mm x mm)	Output Logic	Features
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QFN OSCILLATORS | Pin-compatible QFN | Short lead time even for custom frequencies

SiT8924	1 to 110 MHz	-40 to +85, -40 to +105, -40 to +125, -55 to +125	±20, ±25, ±30, ±50	1.8, 2.5 to 3.3	QFN: 2.0 x 1.6, 2.5 x 2.0, 3.2 x 2.5, 5.0 x 3.2 7.0 x 5.0	LVCMOS	8 output drive strength options, Field Programmable
SiT8925	115.2 to 137 MHz						
SiT8934	1 to 150 MHz	-40 to +85, -40 to +105, -40 to +125, -55 to +125	±20, ±25, ±30, ±50	1.8, 2.5 to 3.3	QFN with wettable flank: 2.0 x 1.6, 2.5 x 2.0, 3.2 x 2.5, 5.0 x 3.2 7.0 x 5.0	LVCMOS	8 output drive strength options, Field Programmable
SiT8935							

SOT23 OSCILLATORS | Best solder-joint reliability | Short lead time even for custom frequencies

SiT2024	1 to 110 MHz	-40 to +85, -40 to +105, -40 to +125, -55 to +125	±20, ±25, ±30, ±50	1.8, 2.5 to 3.3	SOT23-5: 2.9 x 2.8	LVCMOS	8 output drive strength options, Field Programmable
SiT2025	115.2 to 137 MHz						

DIFFERENTIAL OSCILLATORS | Best-in-class jitter | Wide frequency range

SiT9386	1 to 220 MHz	-40 to +85, -40 to +105	±10, ±20, ±25, ±50	2.5, 2.8, 3.0, 3.3	QFN with wettable flank: 3.2 x 2.5, 7.0 x 5.0	LVPECL, LVDS, HCSL	0.23 ps rms phase jitter
SiT9387	220 to 725 MHz						

EMI REDUCTION OSCILLATORS | Most flexible EMI reduction options | Low cycle-cycle jitter

SiT9025	1 to 150 MHz	-40 to +85, -40 to +105, -40 to +125, -55 to +125	±20, ±25, ±50	1.8, 2.5 to 3.3	QFN: 2.0 x 1.6, 2.5 x 2.0, 3.2 x 2.5	LVCMOS	40 spread options, up to ±2.0%, down to -4.0%, Smallest, Field Programmable
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TCXO/VCTCXO/DCTCXO | ±6.25 to ±3200 ppm pull range | 5 ppt resolution frequency control

SiT5186	1 to 220 MHz	-40 to +85, -40 to +105	±0.5, ±1, ±2.5	2.5, 2.8, 3.0, 3.3	SMD: 5.0 x 3.2	LVCMOS, Clipped Sinewave	I2C programmable, 1 ppb/°C slope, Field Programmable
SiT5187			±0.1, ±0.2, ±0.25 ⁽¹⁾				
SiT5386							
SiT5387							

32 KHZ OSCILLATORS | Small size | Low power | Reliable startup in cold temperature

SiT1680	32.768 kHz	-40 to 85, -40 to 105	±3, ±5, ±10, ±20, ±100, ±150	1.5 to 3.63	CSP: 1.5 x 0.8	LVCMOS, NanoDrive™	Smallest XO/TCXO
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⁽¹⁾ Contact SiTime for ±50 ppb

Field Programmable Oscillators – Always Available



ANY FREQUENCY



ANY VOLTAGE



ANY STABILITY



Easy-to-use programming kit

- Don't waste time searching & waiting for timing devices
- Optimize system performance with custom frequencies
- Instantly reduce EMI with programmable drive strength